

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74VCX162721FT****LOW-VOLTAGE 20-BIT D-TYPE FLIP-FLOP  
WITH 3.6 V TOLERANT INPUTS AND OUTPUTS**

The TC74VCX162721FT is a high performance CMOS 20-bit D-TYPE FLIP-FLOP. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

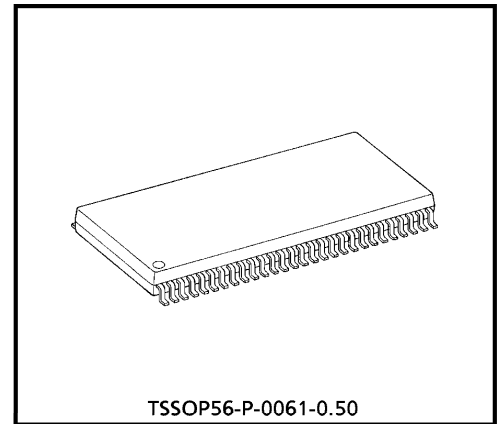
It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

The TC74VCX162721FT is edge-triggered D-type flip-flop with qualified clock storage. On the positive transition of the clock (CK) input, the device provides true data at the Q outputs if the clock-enable ( $\overline{\text{CKEN}}$ ) input is low. If  $\overline{\text{CKEN}}$  is high, no data is stored.

When the  $\overline{\text{OE}}$  input is high, the outputs are in a high impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.



TSSOP56-P-0061-0.50

Weight : 0.25 g (Typ.)

**FEATURES**

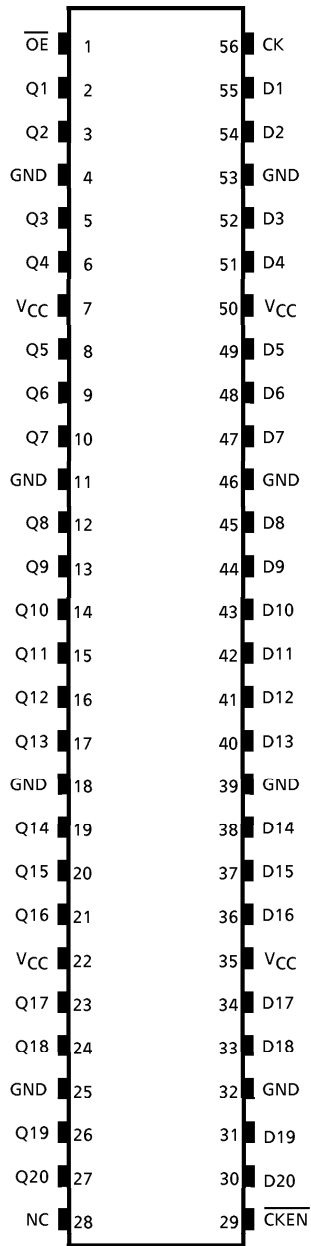
- 26- $\Omega$  Series Resistors on Outputs.
- Low Voltage Operation :  $V_{CC} = 1.8\sim 3.6\text{ V}$
- High Speed Operation :  $t_{pd} = 4.4\text{ ns (max) at } V_{CC} = 3.0\sim 3.6\text{ V}$   
                                   :  $t_{pd} = 5.8\text{ ns (max) at } V_{CC} = 2.3\sim 2.7\text{ V}$   
                                   :  $t_{pd} = 9.8\text{ ns (max) at } V_{CC} = 1.8\text{ V}$
- 3.6V Tolerant inputs and outputs.
- Output Current :  $I_{OH}/I_{OL} = \pm 12\text{ mA (min) at } V_{CC} = 3.0\text{ V}$   
                           :  $I_{OH}/I_{OL} = \pm 8\text{ mA (min) at } V_{CC} = 2.3\text{ V}$   
                           :  $I_{OH}/I_{OL} = \pm 4\text{ mA (min) at } V_{CC} = 1.8\text{ V}$
- Latch-up Performance :  $\pm 300\text{ mA}$
- ESD Performance : Human Body Model  $> \pm 2000\text{ V}$   
                           : Machine Model  $> \pm 200\text{ V}$
- Package : TSSOP  
                           (Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.
- Supports live insertion/withdrawal (Note 1)

(Note 1) : To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

980910EBA2

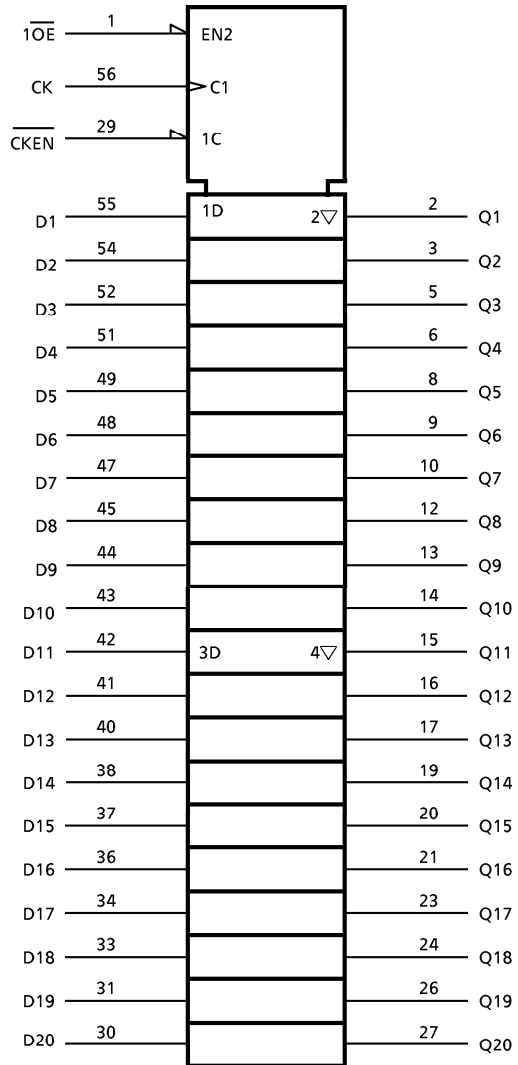
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PIN ASSIGNMENT



(TOP VIEW)

SYMBOL



980910EBA2'

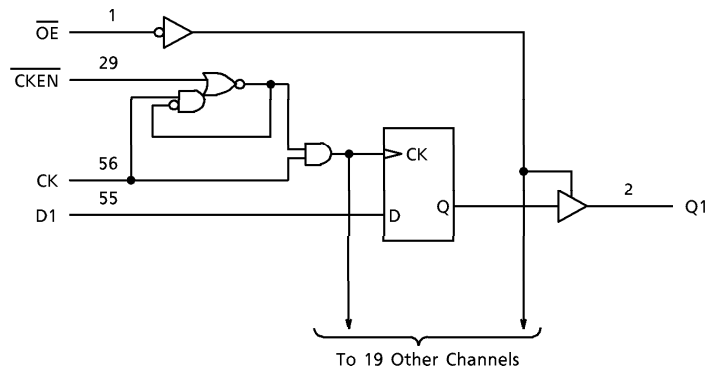
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TRUTH TABLE (each flip flop)

INPUTS				OUTPUTS
$\overline{OE}$	$\overline{CKEN}$	CK	D	Q
L	H	X	X	Q0
L	L	$\downarrow$	H	H
L	L	$\uparrow$	L	L
L	L	L or H	X	Q0
H	X	X	X	Z

X : Don't Care  
 Z : High impedance  
 Qn : No change

**SYSTEM DIAGRAM**



**MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	$V_{CC}$	-0.5~4.6	V
DC Input Voltage	$V_{IN}$	-0.5~4.6	V
DC Output Voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC}$ + 0.5 (Note 2)	
Input Diode Current	$I_{IK}$	-50	mA
Output Diode Current	$I_{OK}$	$\pm 50$ (Note 3)	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
Power Dissipation	$P_D$	400	mW
DC $V_{CC}$ /Ground Current Per Supply Pin	$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage Temperature	$T_{stg}$	-65~150	$^{\circ}C$

(Note 1) : Off-State  
 (Note 2) : High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.  
 (Note 3) :  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	$V_{IN}$	-0.3~3.6	V
Output Voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH}/I_{OL}$	$\pm 12$ (Note 7)	mA
		$\pm 8$ (Note 8)	
		$\pm 4$ (Note 9)	
Operating Temperature	$T_{opr}$	-40~85	$^{\circ}C$
Input Rise And Fall Time	$dt/dv$	0~10 (Note 10)	ns/V

(Note 4) : Data Retention Only

(Note 5) : Off-State

(Note 6) : High or Low State

(Note 7) :  $V_{CC} = 3.0\sim 3.6\text{ V}$ (Note 8) :  $V_{CC} = 2.3\sim 2.7\text{ V}$ (Note 9) :  $V_{CC} = 1.8\text{ V}$ (Note 10) :  $V_{IN} = 0.8\sim 2.0\text{ V}$ ,  $V_{CC} = 3.0\text{ V}$ 

## ELECTRICAL CHARACTERISTICS

DC characteristics ( $T_a = -40\sim 85^{\circ}C$ ,  $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$ )

PARAMETER		SYMBOL	TEST CONDITION		MIN	MAX	UNIT	
								$V_{CC}$ (V)
Input Voltage	"H" Level	$V_{IH}$			2.7~3.6	2.0	V	
	"L" Level	$V_{IL}$			2.7~3.6	—		
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -100\ \mu A$	2.7~3.6	$V_{CC} - 0.2$	—	V
				$I_{OH} = -6\text{ mA}$	2.7	2.2	—	
				$I_{OH} = -8\text{ mA}$	3.0	2.4	—	
				$I_{OH} = -12\text{ mA}$	3.0	2.2	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100\ \mu A$	2.7~3.6	—	0.2	
				$I_{OL} = 6\text{ mA}$	2.7	—	0.4	
				$I_{OL} = 8\text{ mA}$	3.0	—	0.55	
				$I_{OL} = 12\text{ mA}$	3.0	—	0.8	
Input Leakage Current	$I_{IN}$	$V_{IN} = 0\sim 3.6\text{ V}$		2.7~3.6	—	$\pm 5.0$	$\mu A$	
3-State Output Off-State Current	$I_{OZ}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0\sim 3.6\text{ V}$		2.7~3.6	—	$\pm 10.0$	$\mu A$	
Power Off Leakage Current	$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim 3.6\text{ V}$		0	—	10.0	$\mu A$	
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC} \text{ or } GND$		2.7~3.6	—	20.0	$\mu A$	
		$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6\text{ V}$		2.7~3.6	—	$\pm 20.0$		
Increase In $I_{CC}$ Per Input	$\Delta I_{CC}$	$V_{IH} = V_{CC} - 0.6\text{ V}$		2.7~3.6	—	750	$\mu A$	

## ELECTRICAL CHARACTERISTICS

DC characteristics ( $T_a = -40\sim 85^\circ\text{C}$ ,  $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT
Input Voltage	"H" Level	$V_{IH}$			2.3~2.7	1.6	—	V
	"L" Level	$V_{IL}$			2.3~2.7	—	0.7	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\ \mu\text{A}$	2.3~2.7	$V_{CC} - 0.2$	—	V
				$I_{OH} = -4\ \text{mA}$	2.3	2.0	—	
				$I_{OH} = -6\ \text{mA}$	2.3	1.8	—	
				$I_{OH} = -8\ \text{mA}$	2.3	1.7	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\ \mu\text{A}$	2.3~2.7	—	0.2	
				$I_{OL} = 6\ \text{mA}$	2.3	—	0.4	
			$I_{OL} = 8\ \text{mA}$	2.3	—	0.6		
Input Leakage Current		$I_{IN}$	$V_{IN} = 0\sim 3.6\text{ V}$		2.3~2.7	—	$\pm 5.0$	$\mu\text{A}$
3-State Output Off-State Current		$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0\sim 3.6\text{ V}$		2.3~2.7	—	$\pm 10.0$	$\mu\text{A}$
Power Off Leakage Current		$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim 3.6\text{ V}$		0	—	10.0	$\mu\text{A}$
Quiescent Supply Current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND		2.3~2.7	—	20.0	$\mu\text{A}$
			$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6\text{ V}$		2.3~2.7	—	$\pm 20.0$	

## ELECTRICAL CHARACTERISTICS

DC characteristics ( $T_a = -40\sim 85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT
Input Voltage	"H" Level	$V_{IH}$			1.8~2.3	$0.7 \times V_{CC}$	—	V
	"L" Level	$V_{IL}$			1.8~2.3	—	$0.2 \times V_{CC}$	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\ \mu\text{A}$	1.8	$V_{CC} - 0.2$	—	V
				$I_{OH} = -4\ \text{mA}$	1.8	1.4	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\ \mu\text{A}$	1.8	—	0.2	
				$I_{OL} = 4\ \text{mA}$	1.8	—	0.3	
Input Leakage Current		$I_{IN}$	$V_{IN} = 0\sim 3.6\text{ V}$		1.8	—	$\pm 5.0$	$\mu\text{A}$
3-State Output Off-State Current		$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0\sim 3.6\text{ V}$		1.8	—	$\pm 10.0$	$\mu\text{A}$
Power Off Leakage Current		$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim 3.6\text{ V}$		0	—	10.0	$\mu\text{A}$
Quiescent Supply Current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND		1.8	—	20.0	$\mu\text{A}$
			$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6\text{ V}$		1.8	—	$\pm 20.0$	

AC characteristics (Ta = -40~85°C, Input tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	MIN	MAX	UNIT
Maximum Clock Frequency	fMAX	(Fig.1, 2)	1.8	100	—	MHz
			2.5 ± 0.2	200	—	
			3.3 ± 0.3	250	—	
Propagation Delay Time (CK-Q)	tpLH tpHL	(Fig.1, 2)	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.8	
			3.3 ± 0.3	0.6	4.4	
3-State Output Enable Time	tpZL tpZH	(Fig.1, 3)	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.9	
			3.3 ± 0.3	0.6	4.3	
3-State Output Disable Time	tpLZ tpHZ	(Fig.1, 3)	1.8	1.5	8.8	ns
			2.5 ± 0.2	0.8	4.9	
			3.3 ± 0.3	0.6	4.3	
Minimum Pulse Width (CK)	tw (H) tw (L)	(Fig.1, 2)	1.8	4.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum Set-up Time	ts	(Fig.1, 2, 4)	1.8	2.5	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum Hold Time	th	(Fig.1, 2, 4)	1.8	1.0	—	ns
			2.5 ± 0.2	1.0	—	
			3.3 ± 0.3	1.0	—	
Output to Output Skew	tosLH tosHL	(Note 11)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For CL = 50 pF, add approximately 300 ps to the AC maximum specification.

(Note 11) : Parameter guaranteed by design.

$$(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)$$

Dynamic switching characteristics (Ta = 25°C, Input tr = tf = 2.0 ns, CL = 30 pF)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	TYP.	UNIT
Quiet Output Maximum Dynamic VOL	VOLP	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	0.15	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	0.25	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	0.35	
Quiet Output Minimum Dynamic VOL	VOLV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	-0.15	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	-0.25	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	-0.35	
Quiet Output Minimum Dynamic VOH	VOHV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	1.55	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	2.05	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	2.65	

(Note 12) : Parameter guaranteed by design.

Capacitive characteristics (Ta = 25°C)

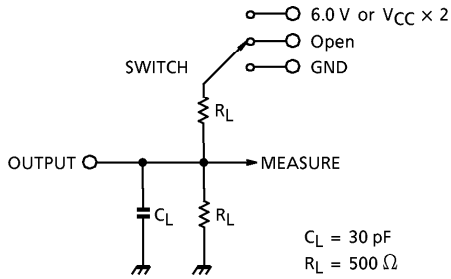
PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	TYP.	UNIT
Input Capacitance	C <sub>IN</sub>		1.8, 2.5, 3.3	6	pF
Output Capacitance	C <sub>O</sub>		1.8, 2.5, 3.3	7	pF
Power Dissipation Capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note 13)	1.8, 2.5, 3.3	60	pF

(Note 13) : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/20 \text{ (per bit)}$$

**TEST CIRCUIT**  
Fig.1



PARAMETER	SWITCH
$t_{pLH}, t_{pHL}$	Open
$t_{pLZ}, t_{pZL}$	6.0 V @ $V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} \times 2$ @ $V_{CC} = 2.5 \pm 0.2 \text{ V}$ @ $V_{CC} = 1.8 \text{ V}$
$t_{pHZ}, t_{pZH}$	GND

**AC WAVEFORM**

Fig.2  $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

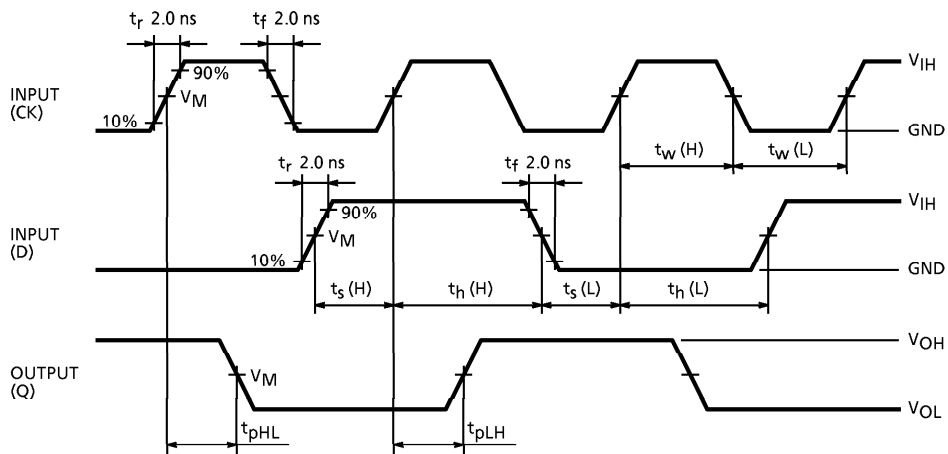
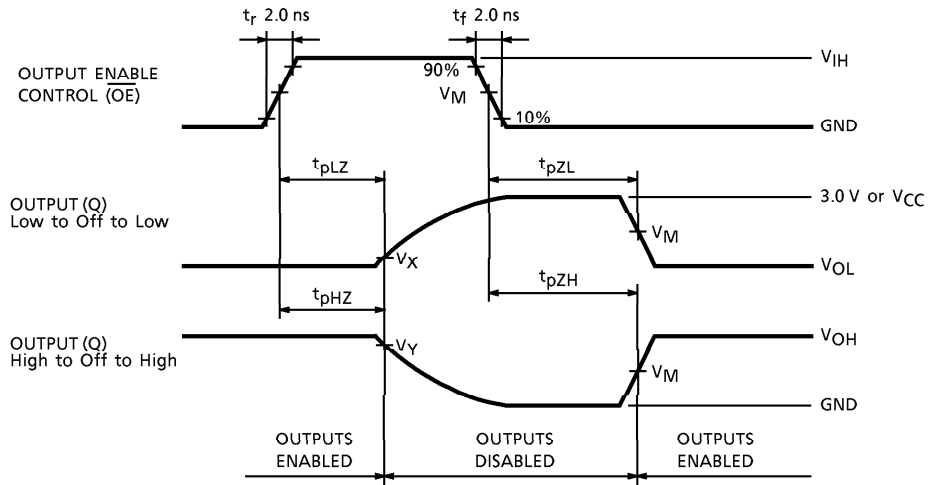


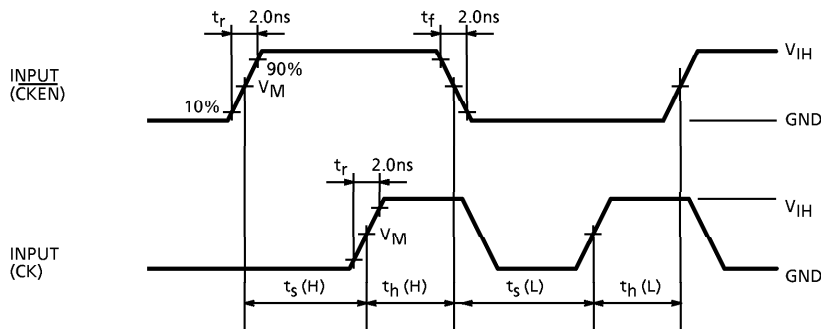


Fig.3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$



SYMBOL	$V_{CC}$		
	$3.3 \pm 0.3 V$	$2.5 \pm 0.2 V$	$1.8 V$
$V_{IH}$	$2.7 V$	$V_{CC}$	$V_{CC}$
$V_M$	$1.5 V$	$V_{CC} / 2$	$V_{CC} / 2$
$V_X$	$V_{OL} + 0.3 V$	$V_{OL} + 0.15 V$	$V_{OL} + 0.15 V$
$V_Y$	$V_{OH} - 0.3 V$	$V_{OH} - 0.15 V$	$V_{OH} - 0.15 V$

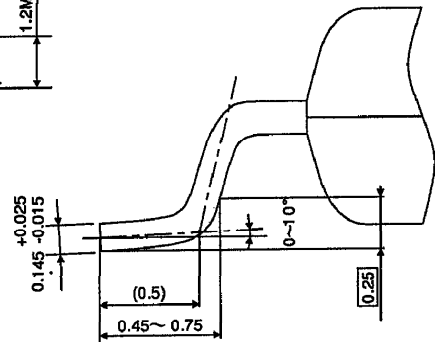
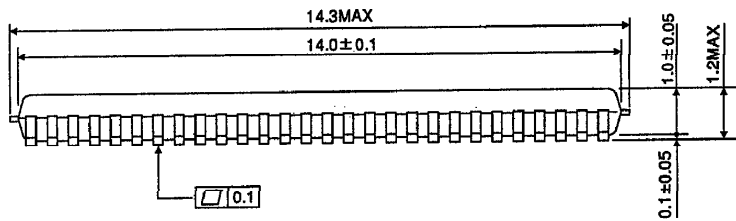
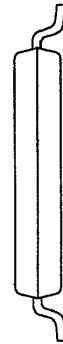
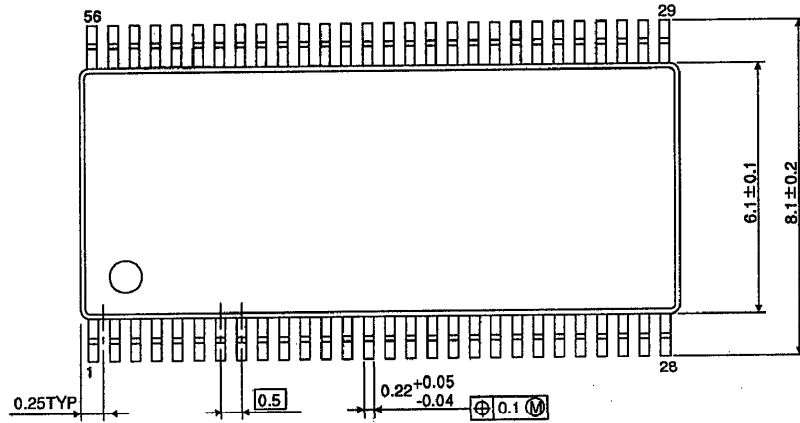
Fig.4  $t_s$ ,  $t_h$



**PACKAGE DIMENSIONS**

TSSOP56-P-0061-0.50

Unit : mm



Weight : 0.25 g (Typ.)